

A novel explanation of increased conductivity in annealed Al-doped ZnO: an insight into migration of aluminum and displacement of zinc: Supplementary data

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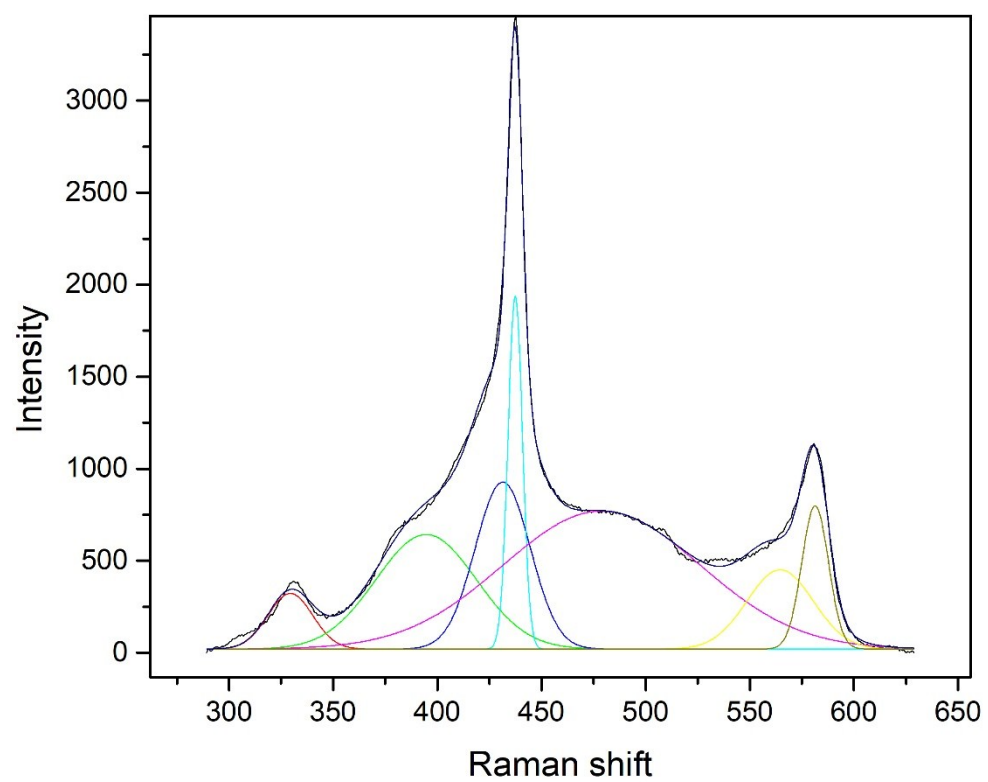
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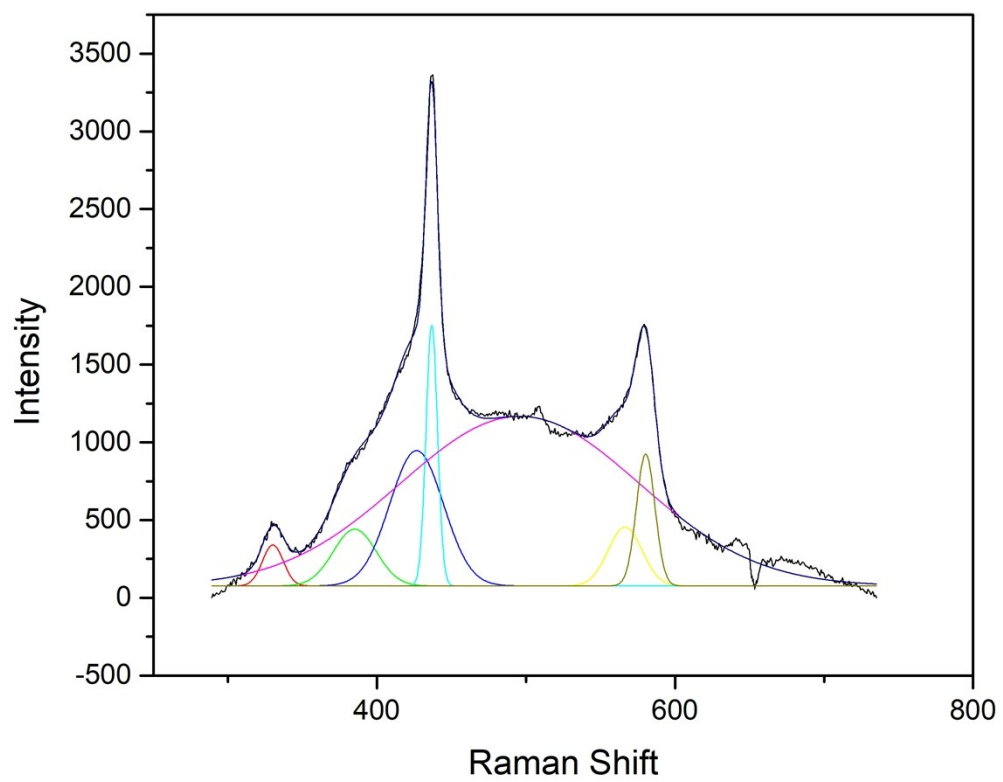
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Raman analysis



S1. Deconvoluted spectrum of as synthesized AZO.



S2. Deconvoluted spectrum of annealed AZO sample